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FORM PTO-1449 (Modified)				ATTY. DOCKET NO.		SERIAL NO.			
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT(S)' INFORMATION DISCLOSURE STATEMENT				02EK-105600		10/807	10/807,605		
	(Use several sheets if necessary)				APPLICANT: Kuo-Chuan Liu, et al.				
					FILING DATE: March 23, 20	GROUP ART UNIT: 1762			
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		OTHER ART (II	nclude Author	r, Titl	e, Date, Pertinent	Pages, E	tc.)		
cc	C1	K.M. Satyalakshmi, et al., "Epitaxial metallic LaNiO ₃ thin films grown by pulsed laser deposition," Appl. Phys. Lett. 62:11 (1993) 1233–1235.							
	C2	C.C. Yang, et al., "Preparation of (100)-oriented metallic LaNiO ₃ thin films on Si substrates by radio frequency magnetron sputtering for the growth of textured Pb(Zr _{0.53} Ti _{0.47})O ₃ ," Appl. Phys. Lett. 66:20 (1995) 2643–2645.							
	C3	Y.L. Tu, et al., "Synthesis and Electrical Characterization of Thin Films of PT and PZT Made from a Diol-Based Sol-Gel Route," J. Am. Ceram. Soc. 79:2 (1996) 441–448.							
	C4	A. Li, et al., "Preparation of perovskite conductive LaNiO ₃ films by metalorganic decomposition," <i>Appl. Phys. Lett.</i> 68:10 (1996) 1347–1349.							
	C5	M.S. Chen, et al., "Effect of textured LaNiO ₃ electrode on the fatigue improvement of Pb(Zr _{0.53} Ti _{0.47})O ₃ thin films," Appl. Phys. Lett. 68:10 (1996) 1430–1432.							
	C6	T.F. Tseng, et al., "Effect of LaNiO ₃ /Pt double layers on the characteristics of (Pb _x La _{1-x})(Zr _y Ti _{1-y})O ₃ thin films," Appl. Phys. Lett. 68:18 (1996) 2505-2510.							
1	C7	A. Li, et al., "Preparation of epitaxial metallic LaNiO ₃ films on SrTiO ₃ by metalorganic decomposition for the oriented growth of PbTiO ₃ ," Appl. Phys. Lett. 69:2 (1996) 161–163.							

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OTHER ART (Include Author, Title, Date, Pertinent Pages, Etc.) T. Yu, et al., "Epitaxial Pb(Zr_{0.53}Ti_{0.47})O₃/LaNiO₃ heterostructures on single crystal C8 CL substrates," Appl. Phys. Lett. 69:14 (1996) 2092-2094. Y.L. Tu, et al., "Processing and characterization of Pb(Zr, Ti)O₃ films, up to 10 μm C9 thick, produced from a diol sol-gel route," J. Mater. Res. 11:10 (1996) 2556-2564. A. Li, et al., "Fabrication and electrical properties of sol-gel derived BaTiO3 films C10 with metallic LaNiO₃ electrode," Appl. Phys. Lett. 70:12 (1997) 1616-1618. C. R. Cho, et al., "Solution deposition and heteroepitaxial crystallization of LaNiO₃ C11 electrodes for integrated ferroelectric devices," Appl. Phys. Lett. 71:20 (1997) 3013-3015. R. Kurchania, et al., "Synthesis of (Pb,La) (Zr,Ti)O₃ films using a diol based sol-gel C12 route," J. Mater. Sci. 33 (1998) 659-667. C.H. Lin, et al., "Domain structure and electrical properties of highly textured C13 PbZr_xTi_{1-x}O₃ thin films grown on LaNiO₃-electrode-buffered Si by metalorganic chemical vapor deposition," J. Mater. Res. 15:1 (2000) pp. 115-124. S.S. Kim, et al., "Structures and properties of (001)-oriented Pb(Zr,Ti)O₃ films on C14 LaNiO₃/Si(001) substrates by pulsed laser deposition," J. Mater. Res. 15:12 (2000) 2881-2886. G.S. Wang, et al., "Properties of highly (100) oriented Ba_{0.9}Sr_{0.1}TiO₃/LaNiO₃ C15 heterostructures prepared by chemical solution routes," Appl. Phys. Lett. 78:26 (2001) 4172-4174.

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